

L Number	Hits	Search Text	DB	Time stamp
1	2917	((438/5) or (438/6) or (438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18) or (324/719)).CCLS.	USPAT; US-PGPUB	2004/05/31 09:27
2	0	((438/5) or (438/6) or (438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18) or (324/719)).CCLS.) and input near3 match\$3 and power adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/31 09:27
-	1630	power adj transistor.ti,ab. and amplifier.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 17:50
-	222	power adj transistor.ti. and amplifier.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 08:48
-	23	power adj transistor.ti. and amplifier.ti. and (rf or radio adj frequency).ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:05
-	126	power adj transistor.ti. and (rf or radio adj frequency).ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:07
-	87	power adj transistor.ti. and (rf or radio adj frequency).ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:30
-	220	internal adj matching	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:31
-	48	internal adj matching with transistor.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:34
-	0	(internal adj matching with transistor.ti,ab.) and ldmos	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:35
-	0	(internal adj matching with transistor.ti,ab.) and ldmosfet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:35
-	0	(internal adj matching with transistor.ti,ab.) and mosfet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:35
-	12	(internal adj matching with transistor.ti,ab.) and field adj effect adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 10:35
-	0	JP-2001024148 JP-05218102 JP-04321308 JP-01283951 JP-02005459 JP-01199436 JP-63086904 JP-55091148	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:12

	14	JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did. JP-55091148\$-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:13
	10	((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:14
	4	EP-680141\$-\$.did. JP-01050602\$-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:15
	0	((JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did. JP-55091148\$-\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608"))).PN.) or (EP-680141\$-\$.did. JP-01050602\$-\$.did.) and substrate and transistor and input adj matching and lead and wir\$3 and impedance and (die or dice or chip)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:17
	0	((JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:17
	8	JP-55091148\$-\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608"))).PN.) or (EP-680141\$-\$.did. JP-01050602\$-\$.did.) and substrate and transistor and input adj matching and lead and wir\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:17
	8	((JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did. JP-55091148\$-\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608"))).PN.) or (EP-680141\$-\$.did. JP-01050602\$-\$.did.) and substrate and transistor and match\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:17

	2	((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 and lead\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:18
	2	((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 and lead\$1 and wir\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 12:18
	2	((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 and lead\$1 and wir\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 13:41
	1	((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and (wir\$3 with impedance) match\$3 and lead\$1 and wir\$3 and impedance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 13:43
	4393	(wir\$3 with impedance).ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 13:43
	207	(wir\$3 with impedance).ti,ab. and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 13:44
	13	(bonding adj2 wir\$3 near5 impedance).ti,ab. and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:39
	3	5371405.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:40
	2	6281756.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:42

-	545	257/664	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:43
-	27	(JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608"))).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:44
-	0	jp-404048756\$-\$\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:45
-	2	jp-04048756\$-\$\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:48
-	1768	257/700	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:48
-	742	257/728	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:48
-	16	(257/664 or 257/700 or 257/728) and wir\$3 and substrate and power adj transistor and matching and impedance	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/10 16:50
-	212	trench same gate same high adj voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/11 07:57
-	46	trench same gate same high adj voltage and field adj effect adj transistor and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/11 07:58
-	6	(trench.ti.ab. same gate same high adj voltage) and field adj effect adj transistor and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/01/11 07:59
-	2937	257/664 or 257/700 or 257/728	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/30 15:50
-	33	(257/664 or 257/700 or 257/728) and impedance near12 (tailor or tailored or adjust or adjustment)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/30 15:52
-	8	(257/664 or 257/700 or 257/728) and impedance near12 (tailor or tailored or adjust or adjustment) and (length or number) near12 wire	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/30 16:16

-	325	impedance near12 (tailor or tailored or adjust or adjustment) and (length or number) near12 wire	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/30 16:17
-	227	impedance near6 (tailor or tailored or adjust or adjustment) and (length or number) near6 wire	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/30 16:18
-	11	impedance near4 (tailor or tailored or adjust or adjustment) and (length or number) near4 wire and (variance or rms or root-mean-square or root adj mean adj square)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/30 16:19
-	2	("5371405").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/02 09:33
-	2	("6281756").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/02 09:38
-	0	("jp-4048756").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/02 09:38
-	0	jp-04048756	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/02 09:38
-	2	jp-04048756\$=\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/02 09:38
-	1135	impedance near6 (match or matching or matched) near6 (wire or wiring)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 17:10
-	488	impedance adj matching near6 (wire or wiring)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 17:10
-	47	impedance adj matching near6 (wire or wiring) and (257/\$6.ccls. or 438/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 19:45
-	0	trimmable near2 (bonding or bond) near2 (wire or wiring)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 19:46
-	5	trimmable near12 (bonding or bond) near12 (wire or wiring)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 19:58
-	8	trimmable adj (resistance or resistor) near3 laser and (257/\$6.ccls. or 438/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 20:08

	0	trimmable adj (resistance or resistor) near6 laser near6 (wire or wiring) and (257/\$6.ccls. or 438/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 20:04
	5	trimmable adj (resistance or resistor) near6 (wire or wiring) and (257/\$6.ccls. or 438/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 20:04
	20	trimmable adj (resistance or resistor) near3 laser.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 20:19
	0	trimmable adj (resistance or resistor) near3 wire.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 20:19
	0	trimmable adj wire.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 20:19
	8365	(trimmablele adj resistor-switch or rs) near12 (wire or wiring)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 08:05
	92	(trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 08:11
	0	(trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test) near12 impedance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 08:11
	27	(trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test) and (438/\$6.ccls. or 257/\$6.ccls. or 324/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 08:33
	287	(secure or securing) near3 (die or chip) near3 substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:00
	2	(secure or securing) near3 (die or chip) near3 substrate and (test or testing or measure or measuring) near3 performance adj characteristic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:02
	2	(secure or securing) near3 (die or chip) near3 substrate and (test or testing or measure or measuring or determine or determining) near3 performance adj characteristic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:09
	8	impedance near3 adjust same length near3 wire	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:09
	37	(resistance or impedance) near3 (adjust or adjustment) same (length near3 (wire or wiring))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:10

-	0	(resistance or impedance) near3 (adjust or adjustment) near12 (length near3 (wire or wiring)) and (die or chip) near12 substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:12
-	1	(resistance or impedance) near3 (adjust or adjustment) near12 (length near3 (wire or wiring)) and (die or chip) same substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:12
-	27	(US-6177801-\$ or US-6084946-\$ or US-6060778-\$ or US-5978449-\$ or US-5864602-\$ or US-5862040-\$ or US-5578931-\$ or US-5528156-\$ or US-5633595-\$ or US-5600240-\$ or US-6389109-\$ or US-5592099-\$ or US-5589780-\$ or US-6417672-\$ or US-6385297-\$ or US-6225811-\$ or US-4320338-\$ or US-3660249-\$ or US-5485093-\$ or US-5250908-\$ or US-4495465-\$ or US-6456088-\$).did. or (US-20020105336-\$).did. or (EP-103971-\$).did. or (JP-01282476-\$ or JP-62272550-\$ or JP-04102345-\$).did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 15:44
-	62	(trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test) not (438/\$6.ccls. or 257/\$6.ccls. or 324/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 16:36
-	4168	((438/10) or (438/11) or (438/13) or (438/17) or (438/18)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 16:37
-	2	((438/10) or (438/11) or (438/13) or (438/17) or (438/18)).CCLS.-and impedance near3 match\$3 and power adj2 (transistor or FET or MOSFET or NMOSFET or CMOSFET or PMOSFET or VMOSFET or UMOSFET or DMOSFET or field adj effect adj transistor) (wire or wiring) near6 (varied or varying) near6 number near12 impedance and power.ti,ab. and (die or chip) and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 16:39
-	0	power adj2 (semiconductor or transistor).ti,ab. and impedance near12 (adjust or adjusting or match or matching) near12 (wire or wiring or lead or leads)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/23 19:05
-	28	(US-5973567-\$ or US-5880517-\$ or US-5696466-\$ or US-5552636-\$ or US-5446959-\$ or US-5023189-\$ or US-4042952-\$ or US-6501159-\$ or US-6177834-\$).did. or (US-20020134993-\$ or US-20010038310-\$ or US-20010004115-\$).did. or (JP-11238851-\$).did. or (EP-1237189-\$ or US-6177834-\$).did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 09:45
-	15	interconnect\$3.ti,ab. and semiconductor.ti,ab. and line adj width	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/01/24 08:45
-	437	(interconnect\$3.ti,ab. and semiconductor.ti,ab. and line adj width) and impedance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 09:47
-	34		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 10:27

-	953	(438/14).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 10:27
-	12	((438/14).CCLS.) and impedance near12 (wire or wiring or interconnect\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 10:38
-	0	impedance near3 matching adj circuit near12 (number near3 wires)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 10:41
-	382	(324/719).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/31 09:25
-	120	impedance near6 wires near6 number	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 10:46
-	0	((324/719).CCLS.) and (impedance near6 wires near6 number)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 10:46
-	6	adjust\$3 near6 impedance near6 wires near6 number	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 10:47
-	7	adjust\$4 near6 impedance near6 wires near6 number	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 11:48
-	2	(("5023189") or ("6331804")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 11:49
-	2	(US-6331804-\$ or US-5023189-\$).did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 11:49
-	18	jp-0600615\$-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/24 11:50
-	8	jp-0600615\$-\$.did.	JPO	2003/01/24 11:50
-	5	813604.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/07 15:02
-	392	input near5 transistor near5 (match matching) near5 impedance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/07 15:20
-	13	(US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5387888-\$ or US-5371405-\$ or US-5696466-\$ or US-6348718-\$ or US-6501159-\$ or US-6479846-\$ or US-6455925-\$ or US-6331804-\$).did. or (US-20010004115-\$ or US-20020134993-\$).did.	USPAT; US-PGPUB	2003/07/07 15:20

	13	((US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5387888-\$ or US-5371405-\$ or US-5696466-\$ or US-6348718-\$ or US-6501159-\$ or US-6479846-\$ or US-6455925-\$ or US-6331804-\$).did. or (US-20010004115-\$ or US-20020134993-\$).did.) and input near5 transistor near5 (match matching) near5 impedance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/07 15:23
	13	((US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5387888-\$ or US-5371405-\$ or US-5696466-\$ or US-6348718-\$ or US-6501159-\$ or US-6479846-\$ or US-6455925-\$ or US-6331804-\$).did. or (US-20010004115-\$ or US-20020134993-\$).did.) and input near5 transistor near5 (match matching) near5 impedance and matching	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/07 17:05
	48	(US-6177834-\$ or US-5880517-\$ or US-5696466-\$ or US-5539254-\$ or US-4042952-\$ or US-5387888-\$ or US-5492842-\$ or US-5563447-\$ or US-5519253-\$ or US-5444295-\$ or US-6501159-\$ or US-5973567-\$ or US-5552636-\$ or US-5446959-\$ or US-6331804-\$ or US-5982793-\$ or US-6479846-\$ or US-6455925-\$ or US-6348718-\$ or US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5371405-\$ or US-5023189-\$ or US-6281756-\$ or US-5576661-\$).did. or (US-5206608-\$).did. or (US-20020134993-\$ or US-20010038310-\$ or US-20010004115-\$).did. or (EP-680141-\$ or US-5206608-\$).did. or (JP-04218949-\$ or JP-07270443-\$ or JP-03114251-\$ or JP-05002316-\$ or JP-11238851-\$ or JP-06006150-\$ or JP-04321308-\$ or JP-02005459-\$ or JP-01199436-\$ or JP-01283951-\$ or JP-63086904-\$ or JP-55091148-\$ or JP-05218102-\$ or JP-2001024148-\$).did. or (EP-1237189-\$ or US-6177834-\$ or JP-01050602-\$).did. ((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/08 07:55
	5156	JP-05002316-\$ or JP-11238851-\$ or JP-06006150-\$ or JP-04321308-\$ or JP-02005459-\$ or JP-01199436-\$ or JP-01283951-\$ or JP-63086904-\$ or JP-55091148-\$ or JP-05218102-\$ or JP-2001024148-\$).did. or (EP-1237189-\$ or US-6177834-\$ or JP-01050602-\$).did. ((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 07:58
	7	((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.) and (rf radio-frequency radio adj frequency) and impedance near12 match\$3 and wir\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:07
	10407	impedance adj matching.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:07
	263	substrate and (die or chip) and (wire-wiring wires)and impedance adj matching.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:09
	5	substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. and ((step steps) near12 order)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:12

-	121	substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:54
-	0	substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. and ("in" adj situ) near6 (test testing measuring measurement)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:55
-	0	substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. and ("in" adj situ) near16 (test testing measuring measurement)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:55
-	0	("in" adj situ) near16 (test testing measuring measurement) same impedance adj matching	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 08:55
-	5161	((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/10 08:02
-	18	((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.) and impedance near20 (match matching) and (wire wiring wires)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/10 08:05
-	3	((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.) and impedance near20 (match matching) and (wire wiring wires) and transistor near20 (chip die)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/10 08:05
-	2	("5023189").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 17:51
-	2	jp-06006150\$-\$did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 18:07
-	0	input adj matching adj element near6 connect\$3 near6 transistor and impedance near6 adjust\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 18:09
-	15	input adj matching near6 connect\$3 near6 transistor and impedance near6 adjust\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 18:10
-	5	813604.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 18:29
-	4865	((438/5) or (438/6) or (438/10) or (438/11) or (438/12) or (438/13) or (438/17) or (438/18)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 18:29
-	0	((438/5) or (438/6) or (438/10) or (438/11) or (438/12) or (438/13) or (438/17) or (438/18)).CCLS.) and impedance and matching and power adj transistor and wiring near6 (impedance inductance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/30 18:30

-	0	((438/5) or (438/6) or (438/10) or (438/11) or (438/12) or (438/13) or (438/17) or (438/18)).CCLS.) and power adj transistor and wiring near6 (impedance inductance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 18:30
-	3	((438/5) or (438/6) or (438/10) or (438/11) or (438/12) or (438/13) or (438/17) or (438/18)).CCLS.) and transistor and wiring near6 (impedance inductance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 18:42
-	22	input adj matching adj element	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 18:43
-	7	input adj matching adj element and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 18:43
-	1	input adj matching adj element and transistor and inductance and (wiring wire wires)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 18:43
-	2	input adj matching adj element and transistor and inductance and (leads wiring wire wires)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 18:45
-	586	(438/10).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 18:46